

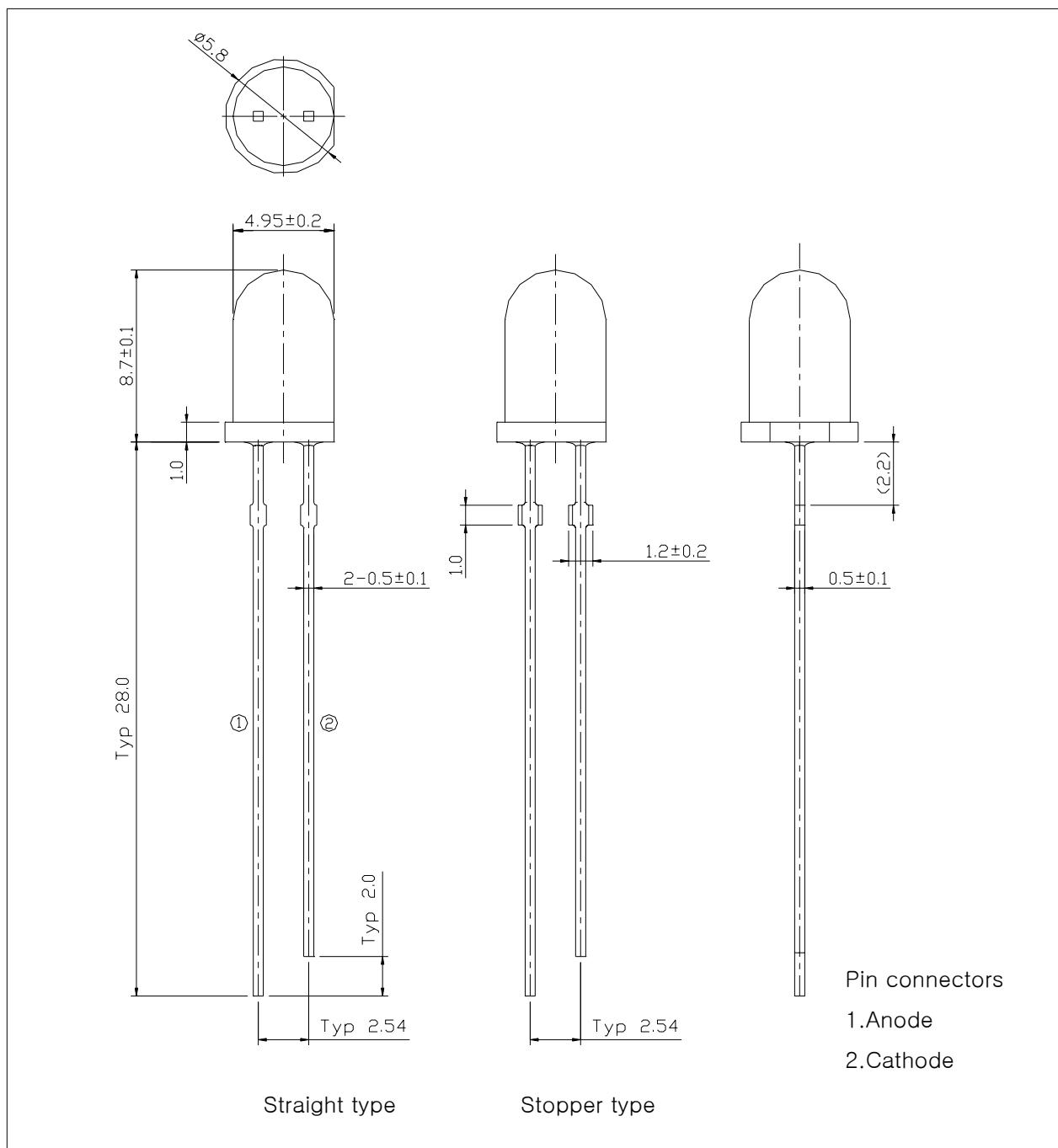


■ Features

- Colorless transparency lens type
- $\phi 5\text{mm}(\text{T}-1\frac{3}{4})$ all plastic mold type
- High Luminosity

■ Outline dimensions

(unit : mm)



■ Absolute Maximum Ratings

Characteristic	Symbol	Ratings	Unit
Power Dissipation	P _D	75	mW
Forward Current	I _F	30	mA
* ¹ Peak Forward Current	I _{FP}	100	mA
Reverse Voltage	V _R	5	V
Operating Temperature	T _{opr}	-30 ~ +85	°C
Storage Temperature	T _{stg}	-40 ~ +100	°C
* ² Soldering Temperature	T _{sol}	260°C for 3 seconds	

*1.Duty ratio = 1/10, Pulse width = 0.1ms

*2.Keep the distance more than 2.0mm from PCB to the bottom of LED package

■ Electrical – Optical Characteristics

(Ta=25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Forward Voltage	V _F	I _F = 20mA	-	2.0	2.7	V
Dominant Wavelength	λ _D	I _F = 20mA	-	624	-	nm
Spectrum Bandwidth	Δλ	I _F = 20mA	-	15	-	nm
Reverse Current	I _R	V _R =5V	-	-	10	uA
* ³ Half Angle	θ _{1/2}	I _F = 20mA	-	±15	-	deg

*3. θ_{1/2} is the off-axis angle where the luminous intensity is 1/2 the peak intensity

■ Luminous intensity ranks

(Ta=25 °C)

Iv RANK	Test Condition	Min.	Typ.	Max.	Unit
Q	I _F = 20mA	1700	–	2400	mcd
R		2400	–	3400	
S		3400	–	4800	
T		4800	–	6700	

* Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of ±11%.

* Intensity Measured : 0.01sr(CIE. LED_B)

■ Precautions On LED using

* To avoid optical difference, Please do not mix differently-ranked product.

■ Characteristic Diagrams

Fig. 1 IF-VF

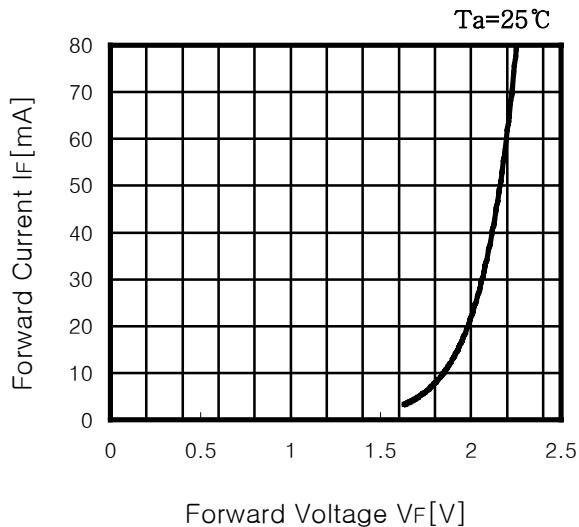


Fig. 2 Iv-If

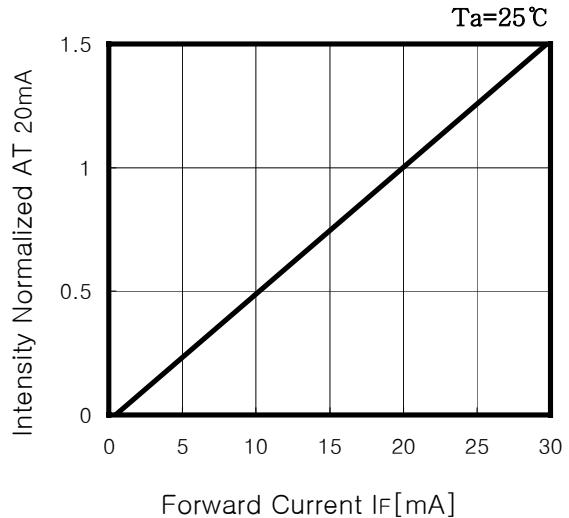


Fig. 3 Spectrum Distribution

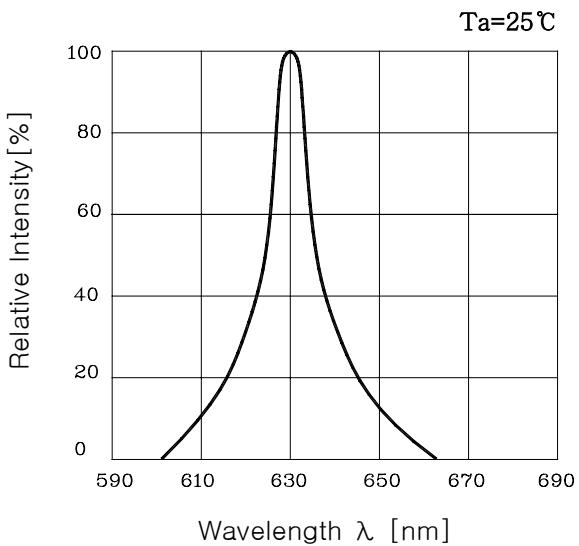


Fig. 4 Relative Intensity-Ta

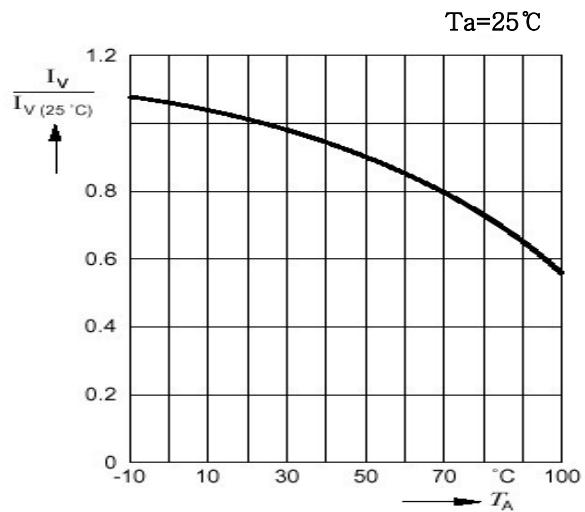
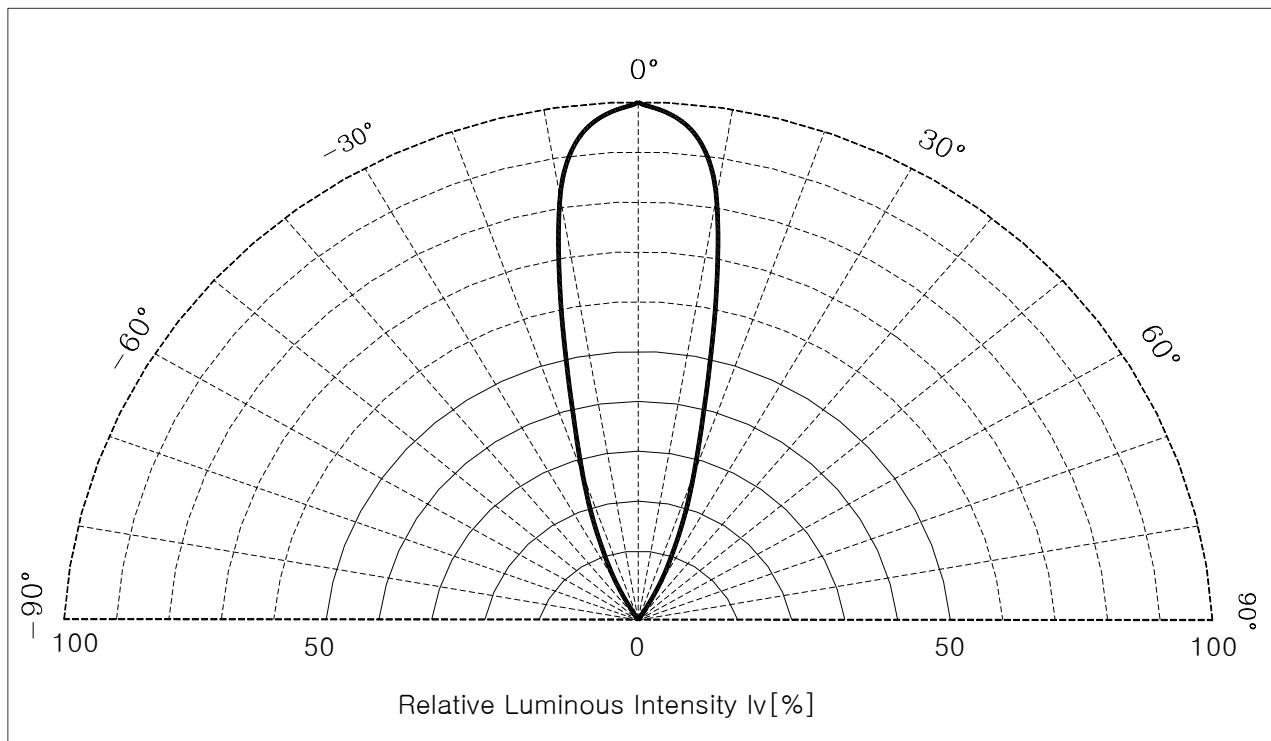


Fig. 5 Radiation Diagram



■ Revision history sheet

Spec NO.			
Title	Specification for Approval		
Times	Date	Summary of revision	Remarks
1	2001. 07. 15	신규제정	
2	2003. 02. 26	Format 변경	